NSN 5962-01-364-8001

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Vsds mh60g gr e/i fscm 7s976
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Hi-performance mos
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
262, 144-word by 4-bit dynamic random-access memory
Voltage Rating And Type Per Characteristic:
-5.0 volts applied and 5.0 volts applied
Time Rating Per Chacteristic:
45.00 nanoseconds access and 150.00 nanoseconds access
Memory Device Type:
Ram
Terminal Type And Quantity:
20 printed circuit
Specification Data:
96906-mil-std-883 government standard
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0